	Тур	e Hits		DBs	Time Stamp
1	BRS	327	bubbler with precursor\$1 ar (CVD or chemical adj vapor adj deposit\$5 or ald or atomic adj layer adj deposit\$5)		2002/04/07
2	BRS	2501	precursor\$1 with (CVD or chemical adj vapor adj deposit\$5 or ald or atomic adj layer adj deposit\$5)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/01 14:25
3	BRS	7	bubbler with organometallic adj precursor\$1 and (CVD or chemical adj vapor adj deposit\$5 or ald or atomic adj layer adj deposit\$5)	USPAT;	2002/04/01 14:30
4	BRS	50	organometallic adj precurso and hydride	USPAT; rUS-PGPUB; JPO; DERWENT	2002/04/01 14:37
5	BRS	7	organometallic adj precurso: with hydride	USPAT; rUS-PGPUB; JPO; DERWENT	2002/04/01 14:42
6	BRS	35	ligand\$1 with organometalliowith hydride	USPAT; US-PGPUB; JPO; DERWENT	2002/04/01 15:04
7	BRS	4351	ligand\$1 near2 (coordin\$8 or associat\$8)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/01 15:06
8	BRS	780	ligand\$1 near2 (coordin\$8 or associat\$8) and (organometallic)	O2-LGLOR;	2002/04/01 15:08
9	BRS	96	ligand\$1 near2 (coordin\$8 or associat\$8) with (organometallic)	US-PGPUB;	2002/04/01
10	BRS :	21	pentane and (ligand\$1 near2 (coordin\$8 or associat\$8) with (organometallic))	USPAT; US-PGPUB; JPO; DERWENT	2002/04/01
11	BRS (	O n	arane	USPAT; US-PGPUB; JPO; DERWENT	2002/04/01 16:26
12	BRS 6	52 t	rimethylamine adj alane	:	2002/04/01

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	Typ	e Hit	Search Text	DBs	Time Stamp
13	BRS	366	liquid\$1 or diluent\$1)	JPO; DERWENT	2002/04/02
14	BRS	0	ligand\$1 near2 (coordin\$8 cassociat\$8) with (organometallic) and (bubbler with (solvent\$1 ordissolv\$3 or inert adjliquid\$1 or diluent\$1))	USPAT; US-PGPUB:	2002/04/01 16:39
15	BRS	9	(ligand\$1 near2 (coordin\$8 or associat\$8)) and (bubble with (solvent\$1 or dissolv\$ or inert adj liquid\$1 or diluent\$1))	USPAT; TUS-PGPUB; JPO; DERWENT	2002/04/02 11:42
16	BRS	0	buchanon.in. with douglas. and international.as.	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 11:43
17	BRS	0	buchanon.in. with douglas.in. and international.as.	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 11:43
18	BRS	7	buchanan.in. with douglas.in. and international.as.	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 11:44
19	BRS		deborah.in. with neumayer.in. and international.as.		2002/04/02 11:54
20	BRS	1	bubbler with (solvent\$1 or dissolv\$3 or inert adj liquid\$1 or diluent\$1) and ((alkane or pentane or hexane or heptane or octane or nonane or decane) with \$methylamine)		2002/04/02 13:21
21	IRRS :	2131 <sup>8</sup>	arccityramilie)		2002/04/02
22	BRS I	1 137 c	dimethylamine or	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 13:24

	Typ	e Hits	Search Text	DBs	Time Stamp
23	BRS	793	(alkane or pentane or hexandor heptane or octane or nonane or decane) with (dimethylamine or diethylamine)	e USPAT; US-PGPUB; JPO; DERWENT	2002/04/02
24	BRS	9	((alkane or pentane or hexane or heptane or octane or nonane or decane) with (dimethylamine or diethylamine)) and (cvd or chemical adj vapor adj deposit\$4)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 13:35
25	BRS	0	(alkane or pentane or hexane or heptane or octane or nonane or decane) with (dimethylamine or diethylamine) and (TDMAT OR TMAT)	USPAT; US-PGPUB; JPO;	2002/04/02 13:30
26	BRS	2353	adj (B or Al or Ga or in or as or sb or boron or	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02 13:35
27	BRS	171	aluminum or gallium or indium or arsenic or antimony) adj hydride) and (cvd or chemical adj vapor adj deposit\$4)	US-PGPUB;	2002/04/07 13:20
28	BRS	256 F	precursor\$1 with (chelat\$5	JPO;	2002/04/02
29	BRS .	29 d	Reposit\$4) with (chelat\$5 or tabiliz\$5 or (coordinat\$8		2002/04/02 14:03

	TI	O Hit-			
	TAD	e Hits	Search Text	DBs	Time Stamp
30	IS& R	2	("5900279").PN.	USPAT; US-PGPUB; JPO; DERWENT	2002/04/02
31	BRS	1	5900279.URPN.	USPAT	2002/04/02 14:03
32	BRS	20	((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl or di-isobutyl) adj (B or Al or Ga or in or as or sb or boron or aluminum or gallium or indium or arsenic or antimony) adj hydride) and (cvd or chemical adj vapor adj deposit\$4) and (solvent\$1 or precursor adj solution\$1)	USPAT;	2002/04/05 09:37
33	IS& R	2	("5820664").PN.	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 10:45
34	BRS	2	neat with precursor\$1 with solvent\$1 with (volume or vol)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03
35	BRS	72	neat with precursor\$1 with solvent\$1	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 10:48
36	BRS	0	((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl or di-isobutyl) adj (Al or aluminum) adj hydride) and (cvd or chemical adj vapor adj deposit\$4) and (solvent\$1 or precursor adj solution\$1) and (codeposit\$3)	.TDO •	2002/04/03 11:51
37	BRS 1	c c a l C	adj (Al or aluminum) adj aydride) and (cvd or		2002/04/03

	ТУК	e Hit	s Search Text	DBs	Time Stamp
3	8 BRS	5 1	((dimethyl or di-methyl or diethyl or di-ethyl or di-isobutyl) adj (Al or aluminum) adj hydride) and (cvd or chemical adj vapor adj deposit\$4) and (codeposit\$3 or co-deposit\$3)	JPO;	2002/04/03 11:51
3	9 BRS	15	precursor\$1 with inert near solvent\$1 and (CVD or chemical adj vapor adj deposition)		2002/04/03
4(	O BRS	17	low adj vapor adj pressure near2 solvent\$1 and (cvd or chemical adj vapor adj deposition)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 12:22
41	BRS	28	(distill\$3 or vaporiz\$3) near1 precursor same bubble	JPO; DERWENT	2002/04/03 14:49
42	BRS	373	(distill\$3 or vaporiz\$3) near1 precursor	JPO; DERWENT	2002/04/03 15:12
43	BRS	5	(distill\$3 or vaporiz\$3) near1 precursor with volume	JPO; DERWENT	2002/04/03 14:51
44	BRS	10	(distill\$3 or vaporiz\$3) nearl precursor with ratio	JPO; DERWENT	2002/04/03 15:12
45	BRS	31	(distill\$3 or vaporiz\$3) near1 precursor adj composition	:	2002/04/03 15:12
46	IS& R	2	("5916359").PN.		2002/04/03
47	BRS		near1 precursor and solvent near2 volume	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 15:24
48	BRS	1	(distill\$3 or vaporiz\$3) near1 precursor and solvent near2 (additive\$1 or	USPAT; US-PGPUB; 2	2002/04/03 L5:26

		T			
	Тур	e Hits	Search Text	DBs	Time Stamp
49	BRS	23	(distill\$3 or vaporiz\$3) near1 precursor and solvent with amine	USPAT; US-PGPUB; JPO; DERWENT	2002/04/03 15:57
50	IS& R	2	("5820664").PN.	JPO; DERWENT	2002/04/03 15:57
51	BRS	34	(((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl) adj (B or Al or Ga or in or as or sb or boron or aluminum or gallium or indium or arsenic or antimony) adj hydride) or DMAH) and (cvd or chemical adj vapor adj deposit\$4) and (solvent\$1 or precursor adj solution\$1)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/05 09:41
52	BRS		(((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl) adj (B or Al or Ga or in or as or sb or boron or aluminum or gallium or indium or arsenic or antimony) adj hydride) or DMAH or alane) and (cvd or chemical adj vapor adj deposit\$4) and (solvent\$1 or precursor adj solution\$1)	JPO; DERWENT	2002/04/05 09:50
53	BRS	8	(((dimethyl or di-methyl or diethyl or di-ethyl or di-isobutyl) adj (B or Al or Ga or in or as or sb or boron or aluminum or gallium or indium or arsenic or antimony) adj hydride) or DMAH or alane) with (hexane or toluene) and (cvd or chemical adj vapor adj deposit\$4)		2002/04/05 09:57
54	BRS :	16 T	viscosity or additive) and (cvd or chemical add vapor	USPAT; US-PGPUB; JPO; DERWENT	2002/04/05

	Тур	e Hits	Search Text	DBs	Time Stamp
55	BRS	117	thd with precursor\$1	USPAT; US-PGPUB; JPO; DERWENT	2002/04/05
56	BRS	124	hfac with precursor\$1	USPAT; US-PGPUB; JPO; DERWENT	2002/04/05 15:10
57	BRS	0	slanticular	USPAT; US-PGPUB; JPO; DERWENT	2002/04/05 15:10
58	BRS	2	slantic\$	USPAT; US-PGPUB; JPO; DERWENT	2002/04/05 15:12
59	BRS	4	slantindicular	USPAT; US-PGPUB; JPO; DERWENT	2002/04/05 15:45
60	BRS	50	tetrahydroguran	USPAT; US-PGPUB; JPO; DERWENT	2002/04/05 15:45
61	BRS	607	precursor\$1 with puls\$3	1	2002/04/07
62	BRS	38	precursor\$1 with puls\$3 and (dram or trench adj capacitor\$1)	:	2002/04/07 10:29
63	BRS	9	precursor\$1 with puls\$3 with (reducing adj agent or hydrogen)	OS EGEOD,	2002/04/07 10:51
64	BRS	15	precursor\$1 with puls\$3 same (reducing adj agent or hydrogen)	US-PGPUB;	2002/04/07
65	BRS	б I	with puls\$3 with (reducing	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07
56	BRS 1	ŗ	precursor\$1 with puls\$3 with pitriding		2002/04/07

	Туре	Hits	Search Text	DBs	Time Stamp
67	BRS	16	precursor\$1 with puls\$3 with purge	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 12:38
68	BRS	35	ferroelectric adj capacitor and tungsten adj plug	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07
69	BRS	149	ferroelectric adj (fet or field adj effect adj transistor\$1)	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:14
70	BRS	10	ferroelectric adj (fet or field adj effect adj transistor\$1) and BST	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:16
71	BRS	25	ferroelectric adj (fet or field adj effect adj transistor\$1) and SBT	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:16
72	BRS	171	· · · · · ·		2002/04/07 13:37
73	BRS	607 ]	precursor\$1 with puls\$3	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:27
74	BRS 1		aluminum or gallium or		2002/04/07 13:25

	Tyr	e Hits	Search Text		T
-	-11		10.10	DBs	Time Stamp
75	BRS	50	((dimethyl or di-methyl or diethyl or di-ethyl or diisobutyl) adj (B or Al or Ga or in or as or sb or boron or aluminum or gallium or indium or arsenic or antimony) adj hydride) and (cvd or chemical adj vapor adj deposit\$4) with hydroger	US-PGPUB; JPO; DERWENT	2002/04/07 13:28
76	BRS	0	precursor\$1 with puls\$3 and alcu	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:28
77	BRS		indium or gallium or indium or arsenic or antimony) adj hydride) and (cvd or chemical adj vapor adj deposit\$4) and alcu	USPAT; US-PGPUB; JPO; DERWENT	2002/04/07 13:34
78	BRS	1	((dimethyl or di-methyl or diethyl or di-ethyl or di-isobutyl) adj (B or Al or Ga or in or as or sb or boron or aluminum or gallium or indium or arsenic or antimony) adj hydride) and (cvd or chemical adj vapor adj deposit\$4) with puls\$3	US-PGPUB;	2002/04/07 13:35
79	BRS	o a 1 a (	((dimethyl or di-methyl or diethyl or di-ethyl or di-isobutyl) adj (B or Al or Ga or in or as or sb or boron or duminum or gallium or arsenic or		2002/04/07

	Туре	Hits		DBs	Time Stamp
80	BRS	10	aluminum or gallium or indium or arsenic or		2002/04/07 13:39